NSN 5961-01-357-3328

Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-357-3328
Inclosure Material:
Metal
Overall Length:
0.185 inches
Terminal Length:
0.500 inches
Overall Diameter:
0.352 inches
Joint Electronic Device Engineering Council/jedec/case Outline Designation:
To-78
Component Name And Quantity:
2 transistor
Mounting Method:
Terminal
Terminal Circle Diameter:
0.200 inches
Semiconductor Material:
Silicon all transistor
Voltage Rating In Volts Per Characteristic:
40.0 breakdown voltage, collector-to-emitter, base open all transistor
Current Rating Per Characteristic:
30.00 milliamperes source cutoff current all transistor
Power Rating Per Characteristic:
400.0 milliwatts small-signal input power, common-collector preset all transistor
Maximum Operating Tempurature Per Measurement Point:
200.0 degrees celsius junction
Special Features:
All transistor junction pattern arrangement: npn
Terminal Type And Quantity:
6 uninsulated wire lead
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No
Fiig:
A110a0